



Docket No.: M4065.0658/P658
(PATENT)

IN THE UNITED STATES PATENT AND TRADEMARK OFFICE

In re Reissue Application of:
Chandra Mouli et al.

Allowed: July 19, 2006

Application No.: 10/648,245

Confirmation No.: 3753

Filed: August 27, 2003

Art Unit: 2878

For: PHOTODIODE WITH ULTRA-
SHALLOW JUNCTION FOR HIGH
QUANTUM EFFICIENCY CMOS
IMAGE SENSOR AND METHOD OF
FORMATION

Examiner: D. N. Monbleau

**COMMENTS ON STATEMENT OF REASONS
FOR ALLOWANCE UNDER 37 C.F.R. §1.104(E)**

MS Issue Fee
Commissioner for Patents
P.O. Box 1450
Alexandria, VA 22313-1450

Dear Sir:

Applicants have received the Examiner's Statement of Reasons for Allowance with the July 19, 2006 Notice of Allowance and Allowability regarding the above-identified application. Entry of the Statement into the record should not be construed as any agreement with or acquiescence in the reasoning stated by the Examiner. Each of the claims stands on its own merits and is patentable because of the combination it recites and not because of the presence or absence of any one particular element.

The Examiner's Statement was not prepared by Applicants and only contains the Examiner's possible positions in one or more reasons for allowability. Thus, any interpretation with respect to the Examiner's Statement of Reasons for Allowance should not be imputed to the Applicants.

Dated: August 22, 2006

Respectfully submitted,

By 

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